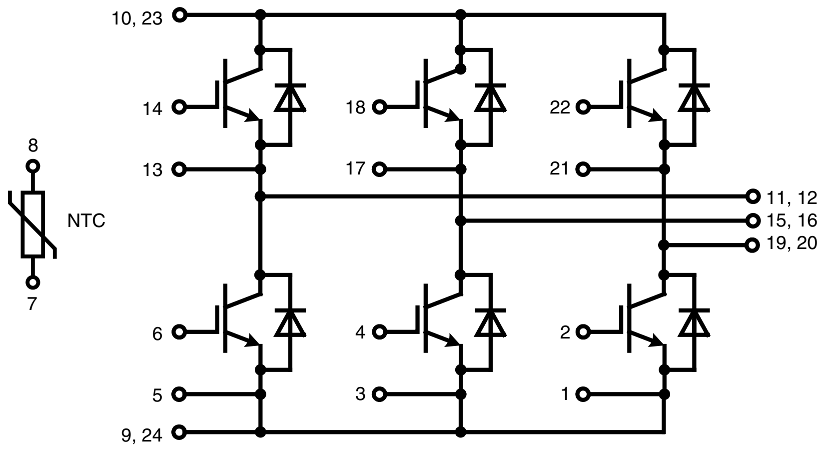
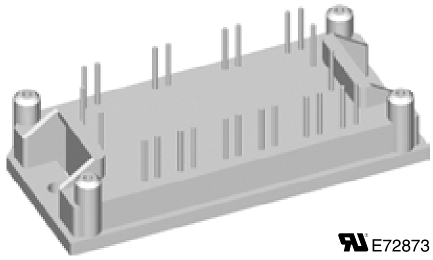
Six-Pack
XPT IGBT

V_{CES} = 1200 V
I_{C25} = 60 A
$V_{CE(sat)}$ = 1.8 V

Part name (Marking on product)

MIXA40W1200TML





Pin configuration see outlines.

Features:

- High level of integration
- Rugged XPT design
  (Xtreme light Punch Through) results in:
  - short circuit rated for 10 µsec.
  - very low gate charge
  - square RBSOA @ 3x I_C
  - low EMI
- Thin wafer technology combined with the XPT design results in a competitive low $V_{CE(sat)}$
- Temperature sense included
- SONIC™ diode
  - fast and soft reverse recovery
  - low operating forward voltage

Application:

- AC motor drives
- Pumps, Fans
- Washing machines
- Air-conditioning system
- Inverter and power supplies

Package:

- E1 package
- Assembly height is 17.1 mm
- Insulated base plate
- Pins suitable for wave soldering and PCB mounting
- UL registered E72873

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IGBT T1 - T6

Symbol	Definitions	Conditions		min.	typ.	max.	Unit
V_{CES}	*collector emitter voltage*		T_{VJ} = 25°C			1200	V
V_{GES} V_{GEM}	*max. DC gate voltage* *max. transient collector gate voltage*	continuous transient				±20 ±30	V V
I_{C25} I_{C80}	*collector current*		T_C = 25°C T_C = 80°C			60 40	A A
P_{tot}	*total power dissipation*		T_C = 25°C			195	W
$V_{CE(sat)}$	*collector emitter saturation voltage*	I_C = 35 A; V_{GE} = 15 V	T_{VJ} = 25°C T_{VJ} = 125°C		1.8 2.1	2.1	V V
$V_{GE(th)}$	*gate emitter threshold voltage*	I_C = 1.5 mA; V_{GE} = V_{CE}	T_{VJ} = 25°C	5.4	5.9	6.5	V
I_{CES}	*collector emitter leakage current*	V_{CE} = V_{CES}; V_{GE} = 0 V	T_{VJ} = 25°C T_{VJ} = 125°C		0.02 0.3	0.15	mA mA
I_{GES}	*gate emitter leakage current*	V_{GE} = ±20 V				500	nA
$Q_{G(on)}$	*total gate charge*	V_{CE} = 600 V; V_{GE} = 15 V; I_C = 35 A			106		nC
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	*turn-on delay time* *current rise time* *turn-off delay time* *current fall time* *turn-on energy per pulse* *turn-off energy per pulse*	inductive load V_{CE} = 600 V; I_C = 35 A V_{GE} = ±15 V; R_G = 27 Ω	T_{VJ} = 125°C		70 40 250 100 3.8 4.1		ns ns ns ns mJ mJ
RBSOA	*reverse bias safe operating area*	V_{GE} = ±15 V; R_G = 27 Ω; V_{CEK} = 1200 V	T_{VJ} = 125°C			105	A
I_{SC} **(SCSOA)**	*short circuit safe operating area*	V_{CE} = 900 V; V_{GE} = ±15 V; R_G = 27 Ω; t_p = 10 μs; non-repetitive	T_{VJ} = 125°C		140		A
R_{thJC} R_{thCH}	*thermal resistance junction to case* *thermal resistance case to heatsink*	(per IGBT)			 0.21	0.64	K/W K/W

Diode D1 - D6

Symbol	Definitions	Conditions		min.	typ.	max.	Unit
V_{RRM}	*max. repetitve reverse voltage*		T_{VJ} = 25°C			1200	V
I_{F25} I_{F80}	*forward current*		T_C = 25°C T_C = 80°C			44 29	A A
V_F	*forward voltage*	I_F = 30 A; V_{GE} = 0 V	T_{VJ} = 25°C T_{VJ} = 125°C		1.95 1.95	2.2	V V
Q_{rr} I_{RM} t_{rr} E_{rec}	*reverse recovery charge* *max. reverse recovery current* *reverse recovery time* *reverse recovery energy*	V_R = 600 V di_F/dt = -600 A/μs I_F = 30 A; V_{GE} = 0 V	T_{VJ} = 125°C		3.5 30 350 0.9		μC A ns mJ
R_{thJC} R_{thCH}	*thermal resistance junction to case* *thermal resistance case to heatsink*	(per diode)			 0.4	1.2	K/W K/W

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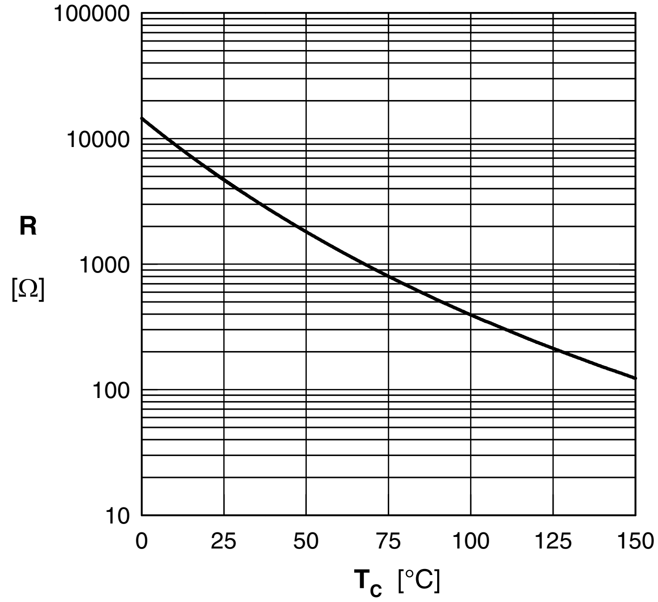
Temperature Sensor NTC

Symbol	Definitions	Conditions	min.	typ.	max.	Unit
				Ratings		
R_{25}	*resistance*	T_C = 25°C	4.75	5.0	5.25	kΩ
$B_{25/50}$				3375		K



Typ. NTC resistance vs. temperature

Module

Symbol	Definitions	Conditions	min.	typ.	max.	Unit
				Ratings		
T_{VJ}	*operating temperature*		-40		125	°C
T_{VJM}	*max. virtual junction temperature*				150	°C
T_{stg}	*storage temperature*		-40		125	°C
V_{ISOL}	*isolation voltage*	$I_{ISOL} \leq 1$ mA; 50/60 Hz			2500	V~
CTI	*comparative tracking index*				-	
F_C	*mounting force*		40		80	N
d_S	*creep distance on surface*		12.7			mm
d_A	*strike distance through air*		12.7			mm
Weight				40		g

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T_C = 25°C unless otherwise stated

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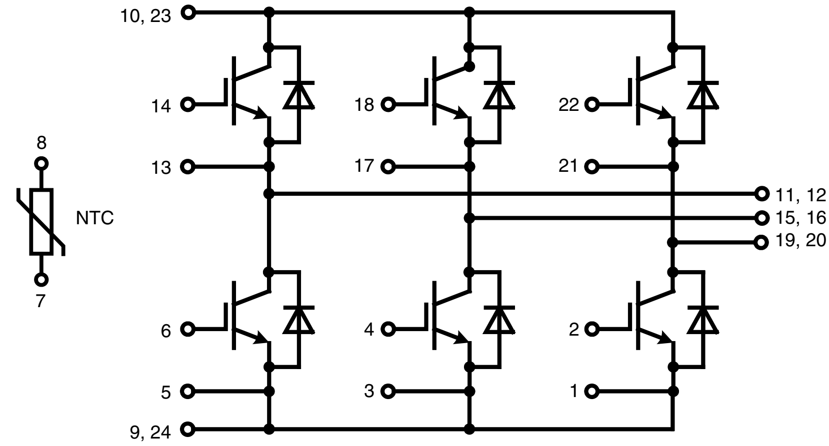
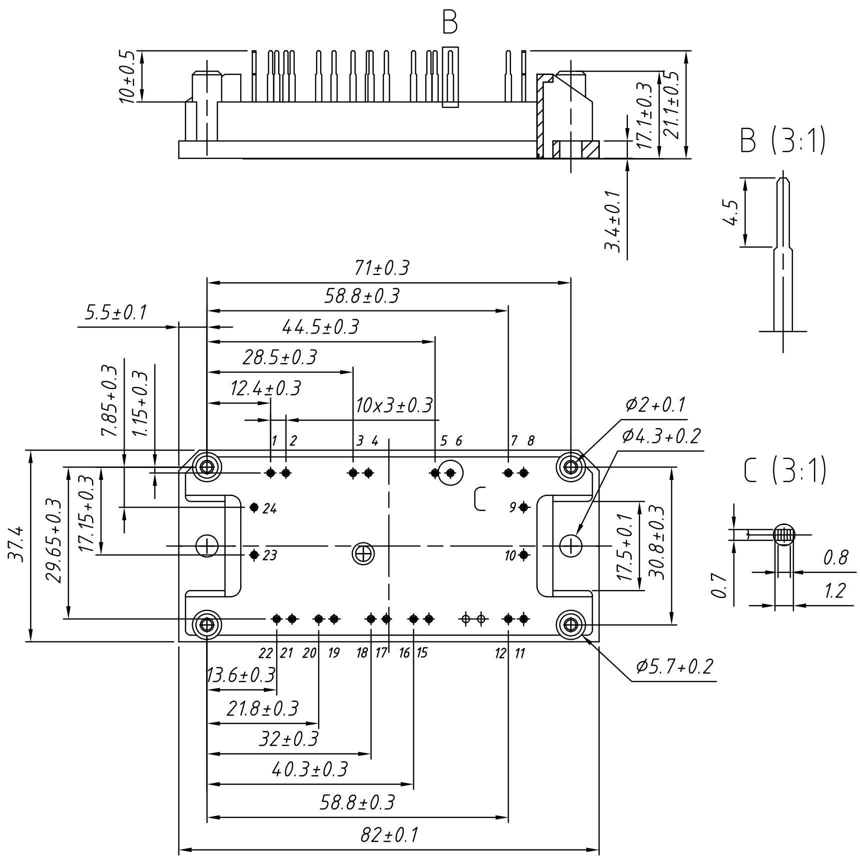
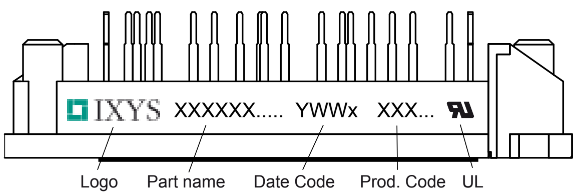
Circuit Diagram



Outline Drawing

Dimensions in mm (1 mm = 0.0394")





Part number

M = Module
I = IGBT
X = XPT
A = standard
40 = Current Rating [A]
W = 6-Pack
1200 = Reverse Voltage [V]
T = NTC
ML = E1-Pack

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Ordering Code
Standard	MIXA 40 W 1200 TML	MIXA40W1200TML	Box	10	510628

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IGBT T1 - T6

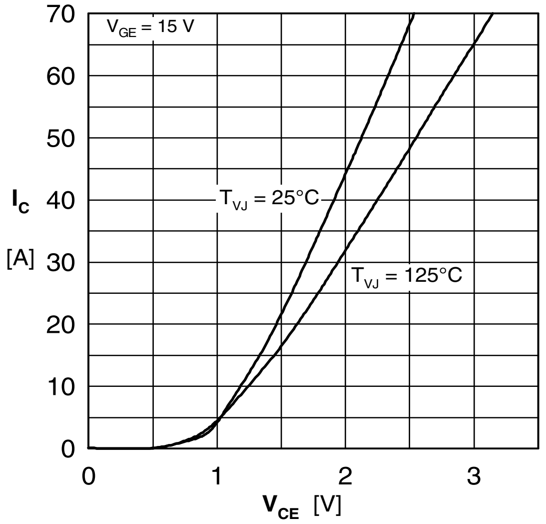

Fig. 1 Typ. output characteristics

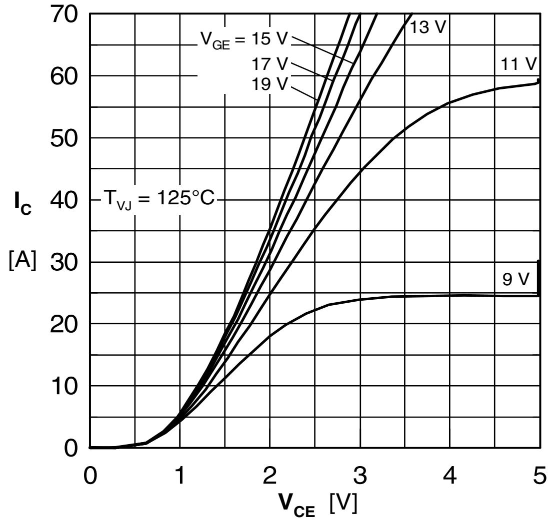

Fig. 2 Typ. output characteristics

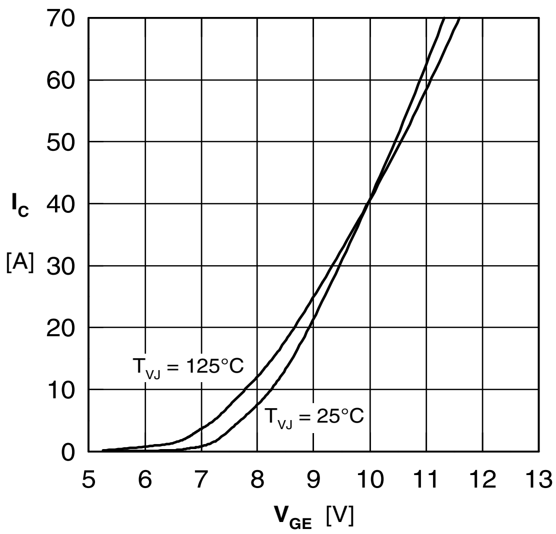

Fig. 3 Typ. tranfer characteristics

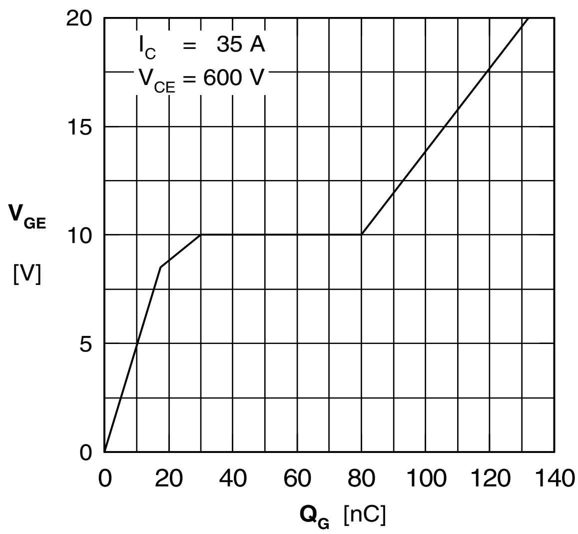

Fig. 4 Typ. turn-on gate charge

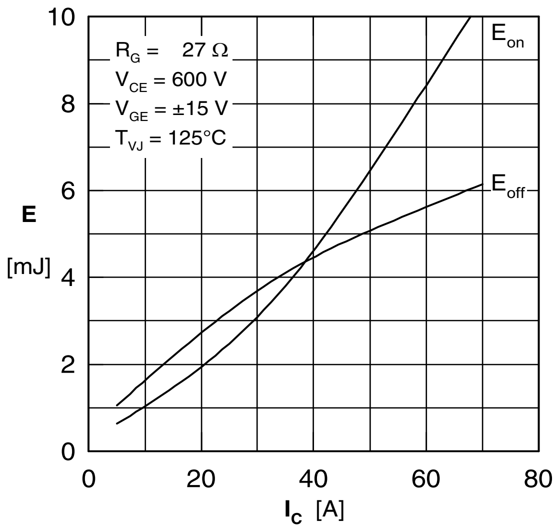

Fig. 5 Typ. switching energy vs. collector current

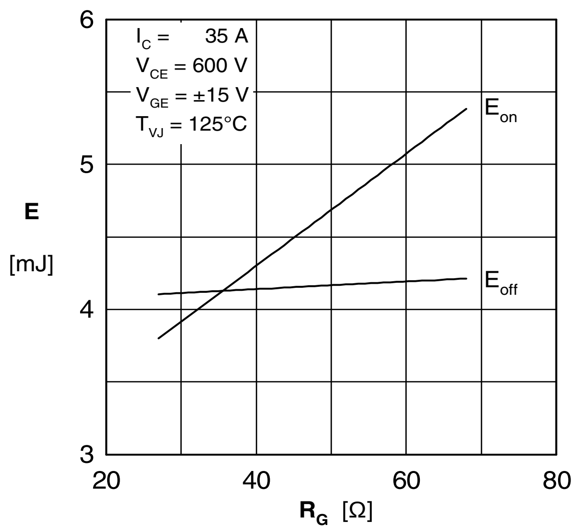

Fig. 6 Typ. switching energy vs. gate resistance

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Diode D1 - D6

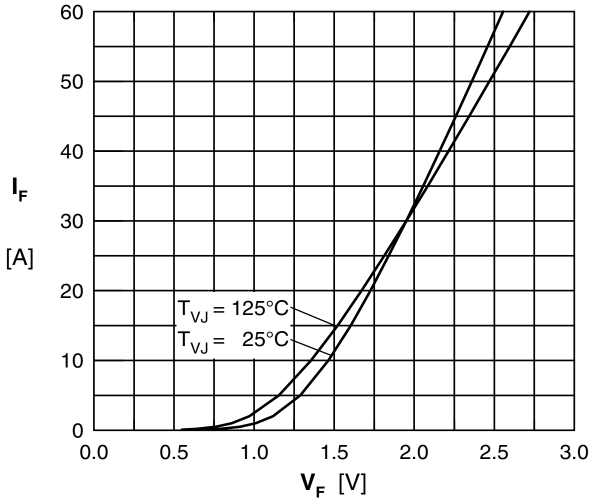


Fig. 7 Typ. Forward current versus V_F

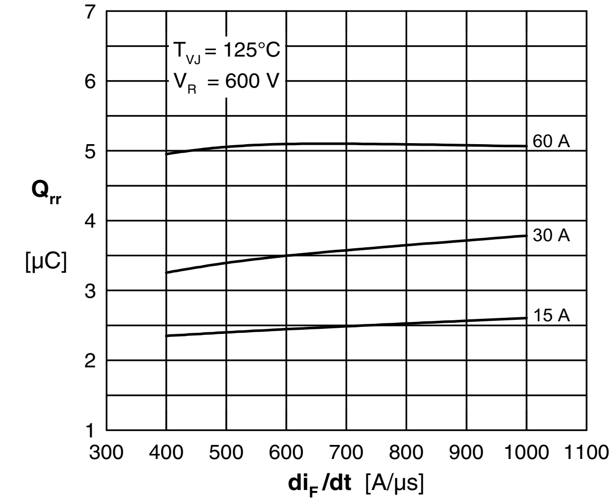


Fig. 8 Typ. reverse recov.charge Q_{rr} vs. di/dt

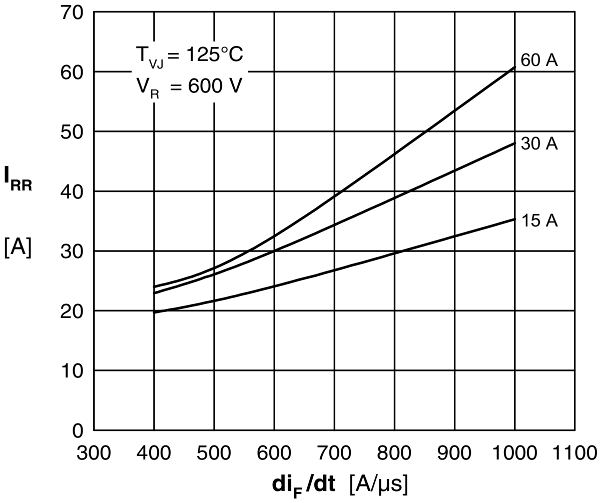


Fig. 9 Typ. peak reverse current I_{RM} vs. di/dt

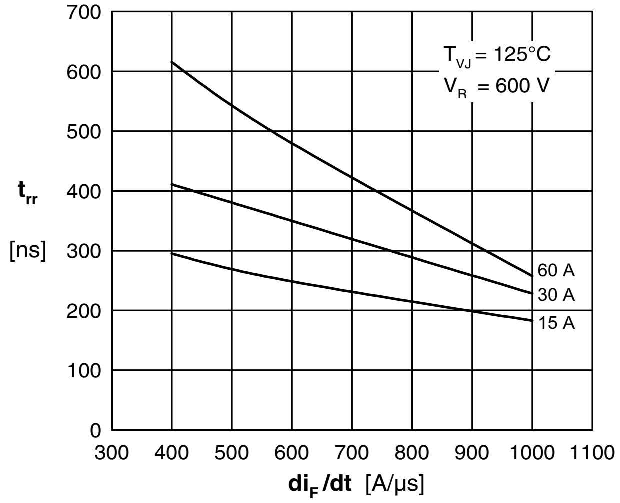


Fig. 10 Typ. recovery time t_{rr} versus di/dt

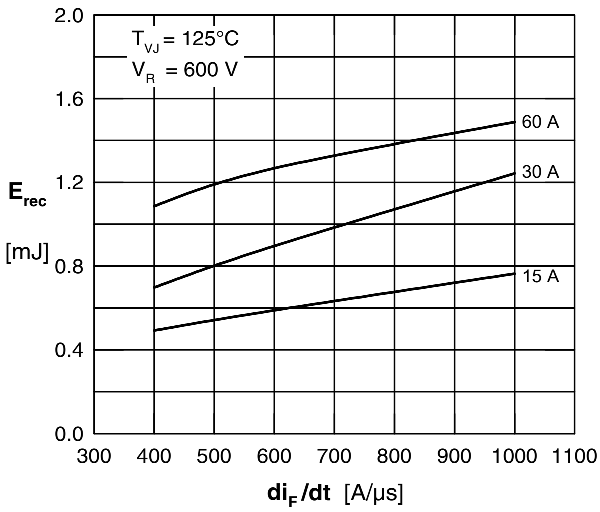
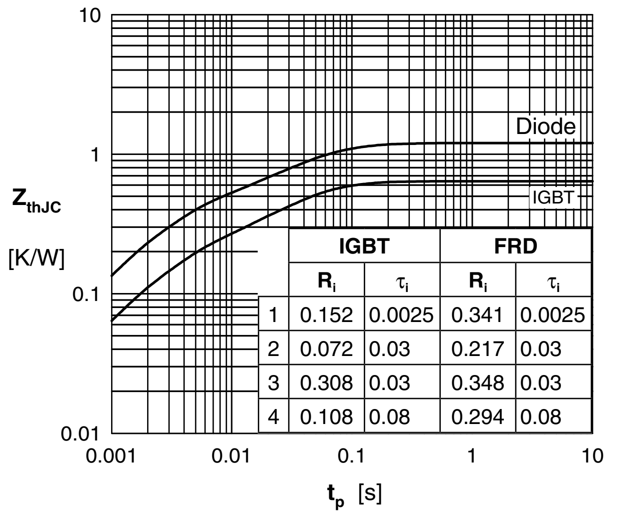


Fig. 11 Typ. recovery energy E_{rec} versus di/dt



	IGBT		FRD	
	R_i	τ_i	R_i	τ_i
1	0.152	0.0025	0.341	0.0025
2	0.072	0.03	0.217	0.03
3	0.308	0.03	0.348	0.03
4	0.108	0.08	0.294	0.08

Fig. 12 Typ. transient thermal impedance

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